

L Number	Hits	Search Text	DB	Time stamp
-	448	438/725.ccls.	USPAT	2003/03/11 12:18
-	91	438/725.ccls. and etch\$3 near5 (poly polysilicon)	USPAT	2003/03/11 12:19
-	15	438/725.ccls. and (sti shallow near trench)	USPAT	2003/03/11 12:26
-	50	(438/725.ccls. and etch\$3 near5 (poly polysilicon)) and organic	USPAT	2003/03/12 09:03
-	5	(438/725.ccls. and (sti shallow near trench)) and organic	USPAT	2003/03/11 12:27
-	7	("4616399"   "5139904"   "5472564"   "5773199"   "5801399"   "5837428"   "6046114").PN.	USPAT	2003/03/11 12:40
-	1	"5759755".PN.	USPAT	2003/03/11 12:49
-	9	("4362809"   "4741926"   "4910122"   "4940508"   "5110697"   "5123998"   "5265177"   "5276126"   "5278010").PN.	USPAT	2003/03/11 12:54
-	1	"5759755".PN.	USPAT	2003/03/11 13:10
-	6	("4620986"   "4910122"   "5326727"   "5472564"   "5514621"   "5545588").PN.	USPAT	2003/03/11 13:45
-	6	("4378628"   "4609930"   "4924294"   "5346860"   "5373169"   "5488246").PN.	USPAT	2003/03/11 13:51
-	10	("Re33622"   "3873361"   "3997367"   "4003044"   "4198261"   "4415402"   "4419809"   "4419810"   "4430791"   "4648937").PN.	USPAT	2003/03/11 13:52
-	50	(438/725.ccls. and etch\$3 near5 (poly polysilicon)) and organic	USPAT	2003/03/12 09:14
-	50	(438/725.ccls. and etch\$3 near5 (poly polysilicon)) and organic	USPAT	2003/03/12 09:14
-	4	("5320975"   "5441914"   "6258727"   "6399515").PN.	USPAT	2003/03/12 09:25
-	10	("4065730"   "4476483"   "4488166"   "4495222"   "4569122"   "4617252"   "5194712"   "5263076"   "5288558"   "5346586").PN.	USPAT	2003/03/12 09:32
-	7	("4341592"   "4885047"   "4904338"   "5071485"   "5094712"   "5169487"   "5201993").PN.	USPAT	2003/03/12 09:34
-	12	("4340462"   "4414057"   "4460435"   "4473436"   "4659426"   "4680086"   "4726879"   "4778563"   "4812418"   "4828649"   "4869781"   "4894693").PN.	USPAT	2003/03/12 09:35
-	19	5201993.URPN.	USPAT	2003/03/12 09:41
-	7	("5094712"   "5169487"   "5201993"   "5346586"   "5378311"   "5795829"   "5897354").PN.	USPAT	2003/03/12 09:43
-	11	("4885106"   "4975144"   "5201993"   "5223443"   "5269879"   "5336365"   "5410174"   "5441901"   "5554565"   "5563098"   "5656128").PN.	USPAT	2003/03/12 09:49
-	5	("4975144"   "5102498"   "5240554"   "5302240"   "5437961").PN.	USPAT	2003/03/12 09:58
-	18	5656128.URPN.	USPAT	2003/03/12 09:59
-	16	("4491628"   "4631328"   "5069997"   "5207952"   "5227444"   "5350660"   "5384378"   "5472827"   "5496899"   "5525457"   "5554489"   "5580700"   "5652297"   "5652317"   "5656128"   "5674356").PN.	USPAT	2003/03/12 10:01
-	12	("4070689"   "4145457"   "4541892"   "4592129"   "4680742"   "4793897"   "4837044"   "4978420"   "5076674"   "5286608"   "5378659"   "5580701").PN.	USPAT	2003/03/12 10:08
-	1	"5437961".PN.	USPAT	2003/03/12 10:10
-	16	5580701.URPN.	USPAT	2003/03/12 10:10
-	6	("5580701"   "5674356"   "5719072"   "5733712"   "5747388"   "5759746").PN.	USPAT	2003/03/12 10:15

-	12	("4053350"   "4426767"   "4620898"   "4704342"   "4975144"   "5017264"   "5022959"   "5102498"   "5185293"   "5240554"   "5445710"   "5498571").PN.	USPAT	2003/03/12 10:35
-	7	5759746.URPN.	USPAT	2003/03/12 10:38
-	7	("5094712"   "5162259"   "5346586"   "5525542"   "5759746"   "5837428"   "5907773").PN.	USPAT	2003/03/12 10:43
-	24	5674356.URPN.	USPAT	2003/03/12 10:56
-	119	("4158717"   "4444617"   "4474975"   "4552783"   "4600671"   "4648904"   "4695859"   "4702936"   "4805683"   "4833096"   "4863755"   "4954867"   "4992306"   "5034348"   "5061509"   "5140390"   "5219613"   "5234869"   "5260600"   "5270267"   "5286661"   "5302366"   "5314724"   "5340621"   "5356515"   "5376591"   "5405489"   "5441797"   "5461003"   "5470772"   "5472827"   "5472829"   "5482894"   "5536857"   "5541445"   "5543654"   "5554567"   "5591494"   "5591566"   "5600165"   "5641607"   "5648202"   "5652187"   "5656330"   "5656337"   "5661093"   "5667015"   "5670297"   "5674356"   "5677015"   "5677111"   "5691212"   "5698352"   "5709741"   "5710067"   "5731242"   "5741721"   "5744399"   "5750442"   "5753320"   "5759755"   "5783493"   "5786039"   "5792689"   "5800877"   "5801399"   "5807660"   "5817549"   "5831321"   "5838052"   "5858880"   "5872035"   "5872385"   "5874367"   "5883011"   "5883014"   "5933721"   "5948482"   "5960289"   "5962581"   "5968324"   "5968611"   "5981368"   "5994730"   "6001741"   "6004850"   "6008121"   "6008124"   "6017779"   "6020243"   "6022404"   "6028015"   "6040619"   "6054379"   "6060765"   "6060766"   "6071799"   "6072227"   "6087267"   "6114255"   "6124641"   "6130168"   "6133096"   "6133613"   "6136636"   "6140151"   "6140677"   "6156674"   "6159804"   "6159871"   "6184151"   "6187657"   "6187694"   "6198144"   "6225217"   "6235568"   "6235591"   "6238976"   "6268282").PN.	USPAT	2003/03/12 10:59
-	10	("5441914"   "5674356"   "5834125"   "5883011"   "6013582"   "6093973"   "6103456"   "6117345"   "6174800"   "6177353").PN.	USPAT	2003/03/12 11:02
-	16	("4491628"   "4631328"   "5069997"   "5207952"   "5227444"   "5350660"   "5384378"   "5472827"   "5496899"   "5525457"   "5554489"   "5580700"   "5652297"   "5652317"   "5656128"   "5674356").PN.	USPAT	2003/03/12 11:21
-	9	("5139904"   "5188704"   "5308742"   "5316616"   "5330883"   "5656128"   "5665203"   "5677111"   "5773199").PN.	USPAT	2003/03/12 11:26
-	43	5441914.URPN.	USPAT	2003/03/12 11:33
-	59772	etch\$3 near5 (poly polysilicon silicon substrate)	USPAT	2003/03/12 12:57
-	366	(etch\$3 near5 (poly polysilicon silicon substrate) ) and organic and (oxy near1 nitride sion)	USPAT	2003/03/13 11:42

-	185	(etch\$3 near5 (poly polysilicon silicon substrate) ) and organic and (oxy near1 nitride sion)	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/13 11:52
-	185	((etch\$3 near5 (poly polysilicon silicon substrate) ) and organic and (oxy near1 nitride sion) ) ((etch\$3 near5 (poly polysilicon silicon substrate) ) and organic and (oxy near1 nitride sion) )	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/13 11:46
-	0	((etch\$3 near5 (poly polysilicon silicon substrate) ) and organic and (oxy near1 nitride sion) ) not ((etch\$3 near5 (poly polysilicon silicon substrate) ) and organic and (oxy near1 nitride sion) )	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/13 11:46
-	185	((etch\$3 near5 (poly polysilicon silicon substrate) ) and organic and (oxy near1 nitride sion) ) not ((etch\$3 near5 (poly polysilicon silicon substrate) ) and organic and (oxy near1 nitride sion) )	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/13 11:46
-	366	(etch\$3 near5 (poly polysilicon silicon substrate) ) and organic and (oxy near1 nitride sion)	USPAT	2003/03/13 11:52
-	26	((etch\$3 near5 (poly polysilicon silicon substrate) ) and organic and (oxy near1 nitride sion) ) and propylene	USPAT	2003/03/13 11:52
-	366	(etch\$3 near5 (poly polysilicon silicon substrate) ) and organic and (oxy near1 nitride sion)	USPAT	2003/03/13 12:02
-	185	(etch\$3 near5 (poly polysilicon silicon substrate) ) and organic and (oxy near1 nitride sion)	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/13 11:53
-	26	((etch\$3 near5 (poly polysilicon silicon substrate) ) and organic and (oxy near1 nitride sion) ) and propylene	USPAT	2003/03/13 12:04
-	59772	etch\$3 near5 (poly polysilicon silicon substrate)	USPAT	2003/03/13 12:02
-	1327	(etch\$3 near5 (poly polysilicon silicon substrate) ) and (oxy near1 nitride sion)	USPAT	2003/03/13 12:03
-	366	((etch\$3 near5 (poly polysilicon silicon substrate) ) and (oxy near1 nitride sion) ) and organic	USPAT	2003/03/13 12:23
-	26	((etch\$3 near5 (poly polysilicon silicon substrate) ) and (oxy near1 nitride sion) ) and organic) and propylene	USPAT	2003/03/13 12:04
-	185	((etch\$3 near5 (poly polysilicon silicon substrate) ) and (oxy near1 nitride sion) ) and organic	US-PGPUB; EPO; JPO; DERWENT	2003/03/13 12:24
-	366	((etch\$3 near5 (poly polysilicon silicon substrate) ) and (oxy near1 nitride sion) ) and organic	USPAT	2003/03/13 12:31
-	13	("4490209"   "5094712"   "5320975"   "5437765"   "5441914"   "5600165"   "5605601"   "5706164"   "5830807"   "5952244"   "5994226"   "6013582"   "6103632").PN.	USPAT	2003/03/13 12:28
-	78	((etch\$3 near5 (poly polysilicon silicon substrate) ) and (oxy near1 nitride sion) ) and organic near2 layer	USPAT	2003/03/13 12:32
-	9	((etch\$3 near5 (poly polysilicon silicon substrate) ) and (oxy near1 nitride sion) ) and organic near2 mask	USPAT	2003/03/13 13:00
-	39	((etch\$3 near5 (poly polysilicon silicon substrate) ) and (oxy near1 nitride sion) ) and organic near5 (arc anti near2 reflective)	USPAT	2003/03/13 12:55
-	6	("5518948"   "5936272"   "6004850"   "6004857"   "6013582"   "6113140").PN.	USPAT	2003/03/13 12:50
-	5	("4663183"   "5569501"   "5986318"   "6007732"   "6054254").PN.	USPAT	2003/03/13 12:58

-	9	((etch\$3 near5 (poly polysilicon silicon substrate) ) and (oxy near1 nitride sion) ) and organic near2 mask ) not ((etch\$3 near5 (poly polysilicon silicon substrate) ) and (oxy near1 nitride sion) ) and organic near2 mask )	US-PGPUB; EPO; JPO; DERWENT	2003/03/13 13:01
-	8	organic near5 (arc anti near2 reflective) same propylene	USPAT	2003/03/13 13:33
-	9	((etch\$3 near5 (poly polysilicon silicon substrate) ) and (oxy near1 nitride sion) ) and organic near2 mask	USPAT	2003/03/13 13:21
-	3	("5824599"   "5976972"   "6153511").PN.	USPAT	2003/03/13 13:25
-	3	("4818715"   "5656523"   "5753557").PN.	USPAT	2003/03/13 13:32
-	0	organic near3 layer same propylene same low near k	USPAT	2003/03/13 13:34
-	0	organic near3 layer same propylene same low near3 constant	USPAT	2003/03/13 13:35
-	2	organic near3 layer same propylene same dielectric near3 constant	USPAT	2003/03/13 13:37
-	149	organic near3 layer same low near4 constant	USPAT	2003/03/13 13:54
-	9	((etch\$3 near5 (poly polysilicon silicon substrate) ) and (oxy near1 nitride sion) ) and organic near2 mask	US-PGPUB; EPO; JPO; DERWENT	2003/03/13 13:38
-	9	(organic near3 layer same low near4 constant) and propylene	USPAT	2003/03/13 13:41
-	18	{"5661344"   "5704067"   "5717251"   "5744865"   "5804508"   "5818111"   "5824599"   "5858869"   "5936295"   "6008540"   "6037668"   "6043146"   "6046503"   "6054769"   "6149778"   "6184121"   "6208030"   "6245672").PN.	USPAT	2003/03/13 13:46
-	7	organic near3 layer same "ch.sub.3 chch.sub.2"	USPAT	2003/03/13 13:53
-	132	organic near3 layer and "ch.sub.3 chch.sub.2"	USPAT	2003/03/13 13:53
-	2	(organic near3 layer and "ch.sub.3 chch.sub.2") and semiconductor	USPAT	2003/03/13 13:53
-	817	organic near3 layer and propylene and semiconductor	USPAT	2003/03/13 13:55
-	1139	organic near3 layer and propylene and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/13 13:55
-	44	(organic near3 layer and propylene and semiconductor) and low near2 (k constant)	USPAT	2003/03/13 13:56
-	0	09386148.ap.	USPAT	2003/05/29 13:31
-	0	"09386148"	USPAT	2003/05/29 13:31
-	0	20020001941A1	USPAT	2003/05/29 13:31
-	0	"20020001941"	USPAT	2003/05/29 13:31
-	0	"2002/0001941"	USPAT	2003/05/29 13:31
-	0	2002/0001941A1.pub.	USPAT	2003/05/29 13:32
-	1	("6420261").PN.	USPAT	2003/05/29 13:34
-	5	((("6420261") or ("6171940") or ("6452274") or ("6479374") or ("6214637"))).PN.	USPAT	2003/05/29 13:34
-	0	("9183507").PN.	USPAT	2003/06/02 06:39
-	0	"09183507"	USPAT	2003/06/02 06:39
-	0	"09590322"	USPAT	2003/06/02 06:40
-	9	"183507"	USPAT	2003/06/02 06:40
-	3	"1154468"	USPAT; EPO	2003/06/02 06:54
-	1	US18350700P	USPAT; EPO	2003/06/02 06:41
-	1	US59032200A	USPAT; EPO	2003/06/02 06:42
-	0	59032200A	USPAT; EPO	2003/06/02 06:42
-	6	"5903220"	USPAT; EPO	2003/06/02 06:42
-	111	fairbairn.in.	USPAT; EPO	2003/06/02 06:43
-	3	fairbairn.in. and amorphous near carbon	USPAT; EPO	2003/06/02 06:46
-	0	("6573030").PN.	USPAT	2003/06/02 06:46
-	1871	depositing near2 amorphous	USPAT; EPO	2003/06/02 06:54
-	8	(depositing near2 amorphous) and fairbairn	USPAT; EPO	2003/06/02 06:54

-	2	"10245741"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/06/03 08:33
-	0	1998JP-10245741	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/06/03 08:35
-	1	1998JP-0245741	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/06/03 08:43
-	1	1999JP-0239528	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/06/03 08:43
-	1	2000-434682.NRAN.	DERWENT	2003/06/03 08:43
-	2	((("6475922") or ("6441914"))).PN.	USPAT	2003/06/04 08:06
-	1	("5441914").PN.	USPAT	2003/06/04 08:09
-	88	etch\$3 near4 (native near oxide) same polysilicon	USPAT	2003/06/04 08:22
-	9	"5837428"	USPAT	2003/06/04 08:23
-	1	("5368989").PN.	USPAT	2003/06/04 10:17
-	1	("6083815").PN.	USPAT	2003/06/04 11:11
-	3485	shallow near trench and nitride same oxide	USPAT	2003/06/04 11:12
-	1617	(shallow near trench and nitride same oxide ) and etch\$3 near3 nitride	USPAT	2003/06/04 11:12
-	1235	(shallow near trench and nitride same oxide ) and etch\$3 near3 nitride and etch\$3 near3 oxide	USPAT	2003/06/04 11:13
-	1760	(shallow near trench and nitride same oxide ) and etch\$3 near3 substrate	USPAT	2003/06/04 11:13
-	776	((shallow near trench and nitride same oxide ) and etch\$3 near3 nitride and etch\$3 near3 oxide) and etch\$3 near3 substrate and silicon	USPAT	2003/06/04 12:35
-	5	{"5981353"   "6001704"   "6020251"   "6066543"   "6087243").PN.	USPAT	2003/06/04 11:14
-	5	{"5981353"   "6001704"   "6020251"   "6066543"   "6087243").PN.	USPAT	2003/06/04 11:18
-	13	((("5459099") or ("4803181") or ("5023203") or ("5811358") or ("6006764") or ("6071821") or ("5902133") or ("6010829") or ("5976769") or ("5837428") or ("5902704") or ("5139904") or ("5776821"))).PN.	USPAT	2003/06/04 13:47
-	0	depost\$3 near5 (carbon near layer)	USPAT	2003/06/04 13:48
-	64	deposit\$3 near5 (carbon near layer) same (nitrogen "n.sub.2")	USPAT	2003/06/04 13:55
-	11	amorphous near3 hydrogen\$3 near3 nitrogen\$3 near5 carbon	USPAT	2003/06/04 13:56